

	Type	Hits	Search Text	DBs	Time Stamp	Comments
1	BRS	1	etching same (Al or aluminum) same barrier same ((first and second) near3 (opening or hole))	USPAT; EPO; JPO; Derwent; IBM TDB	2001/02/08 16:38	
2	BRS	5	etching same (metal\$3) same barrier same ((first and second) near3 (opening or hole))	USPAT; EPO; JPO; Derwent; IBM TDB	2001/02/08 16:16	
3	BRS	68136	etching same mask ((first and second) near3 (opening or via or trench or hole)) same (smaller or larger)	USPAT; EPO; JPO; Derwent; IBM TDB	2001/02/08 16:35	
4	BRS	384527	resistor	USPAT; EPO; JPO; Derwent; IBM TDB	2001/02/08 16:36	
5	BRS	3104	resistor and (etching same mask ((first and second) near3 (opening or via or trench or hole)) same (smaller or larger))	USPAT; EPO; JPO; Derwent; IBM TDB	2001/02/08 16:36	
6	BRS	95856	438/\$.ccls.	USPAT; EPO; JPO; Derwent; IBM TDB	2001/02/08 16:38	
7	BRS	995	438/\$.ccls. and (resistor and (etching same mask ((first and second) near3 (opening or via or trench or hole)) same (smaller or larger)))	USPAT; EPO; JPO; Derwent; IBM TDB	2001/02/08 17:36	
8	BRS	4	"second opening" same (smaller or larger) same "first opening" same resistor	USPAT; EPO; JPO; Derwent; IBM TDB	2001/02/08 17:38	
9	BRS	33	etching same resistor same("thin films" or metallic or metal) same laminated	USPAT; EPO; JPO; Derwent; IBM TDB	2001/02/10 14:06	

	Error Definition	Errors
1		0
2		0
3		0
4		0
5		0
6		0
7		0
8		0
9		0